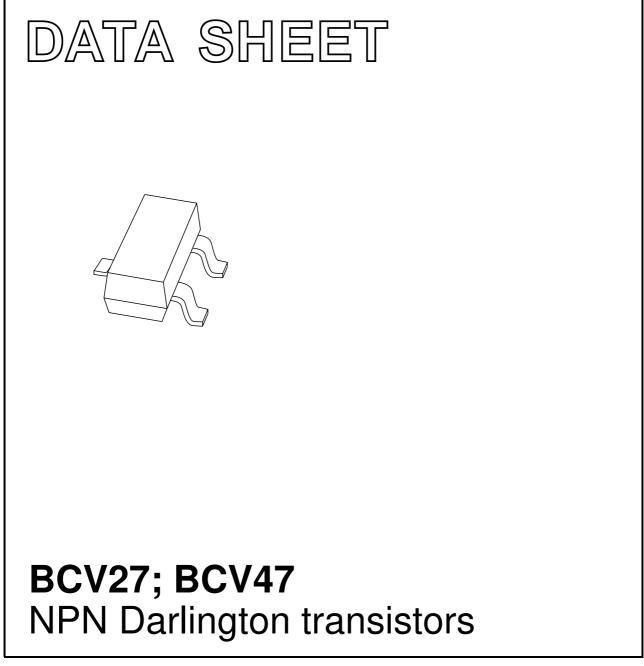
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1999 Apr 08 2004 Jan 13



FEATURES

- Medium current (max. 500 mA)
- Low voltage (max. 60 V)
- High DC current gain (min. 20000).

APPLICATIONS

• Preamplifier input applications.

DESCRIPTION

NPN Darlington transistor in a SOT23 plastic package. PNP complements: BCV26 and BCV46.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
BCV27	FF*
BCV47	FG*

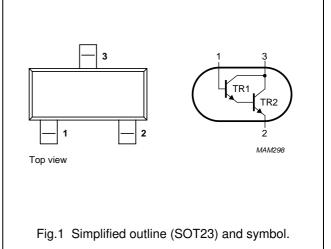
Note

- 1. * = p : Made in Hong Kong.
 - * = t : Made in Malaysia.
 - * = W : Made in China.

ORDERING INFORMATION

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



TYPE	PACKAGE			
NUMBER	NAME DESCRIPTION		VERSION	
BCV27	_	plastic surface mounted package; 3 leads	SOT23	
BCV47				

BCV27; BCV47

BCV27; BCV47

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	BCV27		_	40	V
	BCV47		_	80	V
V _{CES}	collector-emitter voltage	open base			
	BCV27		-	30	V
	BCV47		_	60	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
I _C	collector current (DC)		-	500	mA
I _{CM}	peak collector current		-	800	mA
I _B	base current		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C;$ note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W

Note

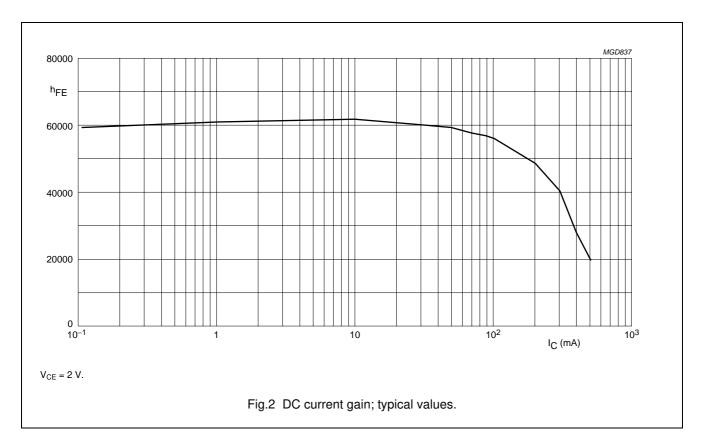
1. Transistor mounted on an FR4 printed-circuit board.

BCV27; BCV47

CHARACTERISTICS

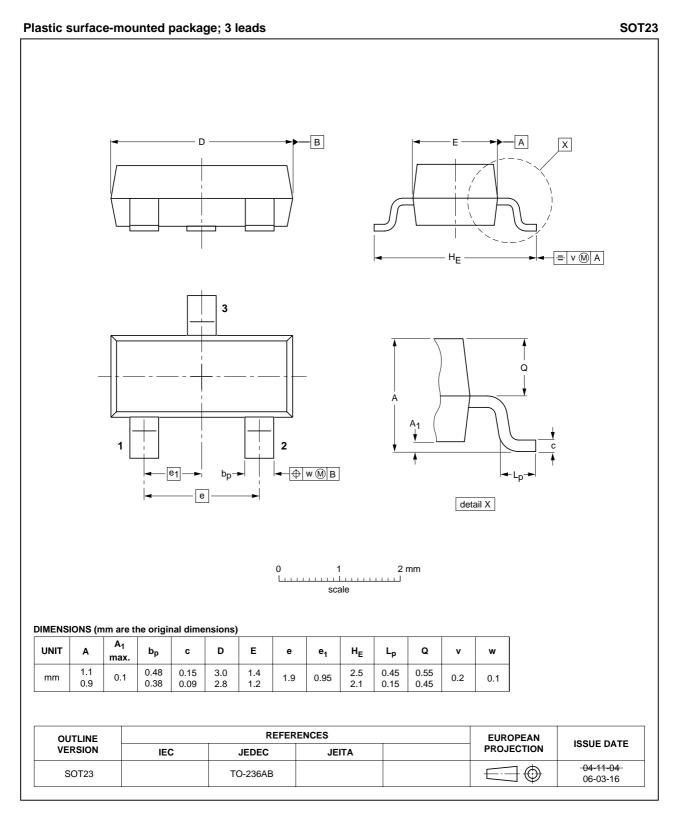
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current					
	BCV27	$I_E = 0; V_{CBO} = 30 V$	-	_	100	nA
	BCV47	$I_E = 0; V_{CBO} = 60 V$	-	_	100	nA
I _{EBO}	emitter cut-off current	I _E = 0; V _{EB} = 10 V	-	_	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; (see Fig.2)				
	BCV27	$I_{\rm C} = 1 \rm{mA}$	4 000	_	_	
		$I_{\rm C} = 10 \rm mA$	10000	_	_	
		I _C = 100 mA	20000	_	_	
	DC current gain	V _{CE} = 5 V; (see Fig.2)				
	BCV47	$I_{\rm C} = 1 \rm{mA}$	2000	_	_	
		$I_{\rm C} = 10 \rm mA$	4 000	_	_	
		I _C = 100 mA	10000	_	_	
V _{CEsat}	collector-emitter saturation voltage	I _C = 100 mA; I _B = 0.1 mA	-	_	1	V
V _{BEsat}	base-emitter saturation voltage	$I_{\rm C} = 100 \text{ mA}; I_{\rm B} = 0.1 \text{ mA}$	-	_	1.5	V
V _{BEon}	base-emitter on-state voltage	$I_{C} = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	-	_	1.4	V
f _T	transition frequency	$I_{C} = 30 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$	_	220	-	MHz



BCV27; BCV47

PACKAGE OUTLINE



BCV27; BCV47

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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